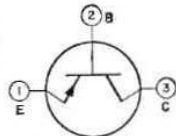


# 2N2614

## TRANSISTOR

Germanium p-n-p type used in a wide variety of small-signal and low-power applications in high-quality audio-frequency amplifier equipment. It is intended primarily for use in low-to-medium-level



audio-amplifier and driver stages. It features a high small-signal forward current-transfer ratio, excellent linearity over the entire range of collector current, high cutoff frequency, low saturation currents, and uniform gain characteristics over the entire audio-frequency spectrum. JEDEC No. TO-1 package; outline 4, Outlines Section.

### MAXIMUM RATINGS

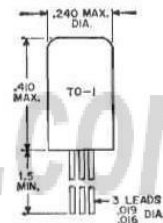
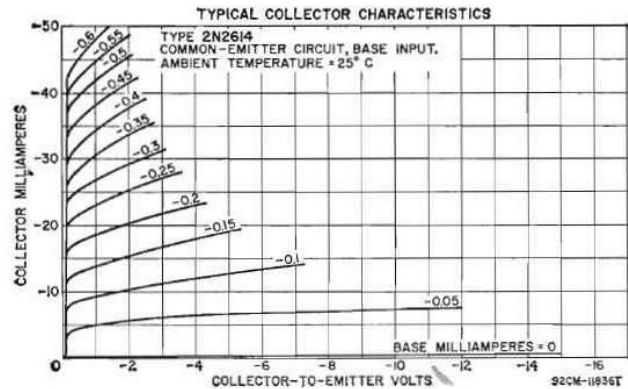
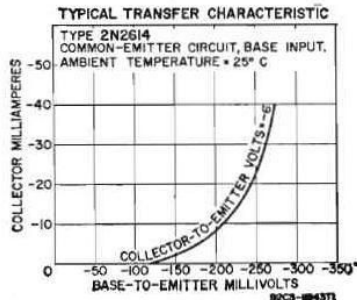
|  |             |       |
|--|-------------|-------|
| Collector-to-Base Voltage  | -40 max     | volts |
| Collector-to-Emitter Voltage (with external base-to-emitter resistance = 10000 ohms) | -35 max     | volts |
| Emitter-to-Base Voltage  | -25 max     | volts |
| Collector Current  | -50 max     | ma    |
| Emitter Current  | 50 max      | ma    |
| Transistor Dissipation:  |             |       |
| At ambient temperatures up to 55°C   | 120 max     | mw    |
| At ambient temperatures above 55°C   | Derate 2.6  | mw/°C |
| At case temperatures up to 55°C with infinite heat sink                              | 300 max     | mw    |
| At case temperatures above 55°C with infinite heat sink                              | Derate 6.67 | mw/°C |
| At case temperatures up to 55°C with typical heat sink                               | 225 max     | mw    |
| At case temperatures above 55°C with typical heat sink                               | Derate 5    | mw/°C |
| Temperature Range:   |             |       |
| Operating (junction) and Storage   | -65 to 100  | °C    |
| Lead Temperature (for 10 seconds maximum)  | 255 max     | °C    |

### CHARACTERISTICS

|  |          |       |
|--|----------|-------|
| Collector-to-Base Breakdown Voltage (with emitter-to-base volts = -2 and collector ma = -0.05)                       | -40 min  | volts |
| Collector-to-Emitter Breakdown Voltage (with collector ma = -1 and external base-to-emitter resistance = 10000 ohms) | -35 min  | volts |
| Emitter-to-Base Breakdown Voltage (with emitter ma = -0.05 and collector current = 0)                                | -25 min  | volts |
| Collector-Cutoff Current (with collector-to-base volts = -20 and emitter current = 0)                                | -5 max   | µa    |
| Emitter-Cutoff Current (with emitter-to-base volts = -20 and collector current = 0)                                  | -7.5 max | µa    |
| Extrinsic Base-Lead Resistance (measured at 20 Mc with collector-to-emitter volts = -6 and collector ma = -1)        | 300      | ohms  |

#### In Common-Emitter Circuit

|   |         |    |
|---|---------|----|
| Small-Signal Forward Current-Transfer Ratio (with collector-to-emitter volts = -6, collector ma = -1 and frequency = 1 kilocycle) | 100 min |    |
| Small-Signal Forward-Current Transfer-Ratio Cutoff Frequency (with collector-to-emitter volts = -6 and collector ma = -1)         | 10      | Mc |
| Collector-to-Base Feedback Capacitance (with collector-to-emitter volts = -6 and collector ma = -1)                               | 9       | pf |



- 4 -